### **One Mark Questions**

#### **Question** 1.

What is biasing of a transistor?

#### Answer:

Tranistor biasing is the application of suitable DC voltages across the transistor terminals.

### **Question** 2.

Why is the transistor called as current controlled device?

#### Answer:

The output current of a transistor depends upon the input current. Hence, the transistor is called as current controlled device.

### **Question** 3.

What is an unbiased transistor?

#### Answer:

A transistor with its terminals not connected to any source is called an unbiased transistor.

### **Question** 4.

Define quiescent point.

### Answer:

The zero signal collector current and collector to emitter voltage is called quiescent point.

### Question 5.

What is meant by dc load line?

### Answer:

Dc load line is a straight line drawn on the output characteristics representing output DC voltage and corresponding direct current under no signal conditions.

### Question 6.

What is thermal runaway?

#### Answer:

The self destruction of an unbiased transistor due to increase in temparature and hence increase in leakage current is called thermal runaway.

#### **Question** 7.

Define stabilisation of a transistor.

#### Answer:

Stabilisation of a transistor is the process of making. Q point independent of transistor parameters and temparature variations.

### Question 8.

Mention any one factor on which stabilisation depends.

#### Answer:

stabilisation depends upon  $\beta$ .

### **Question** 9.

Name any one parameter of the transistor which is temparature dependent. Answer: Leakage current

### **Question** 10.

What is leakage current?

#### Answer:

Leakage current is the current through a device due to the motion of minority charge carriers under reverse biased condition.

### Question 11.

Mention any one leakage current in a transistor. **Answer:** Collector to emitter current with the base open  $I_{CEO}$ .

### Question 12.

Name anyone biasing circuit. **Answer:** 

#### Fired bio

Fixed bias.

### Question 13.

Name the biasing circuit which gives excellent stabilisation.

#### Answer:

Voltage divider biasing circuit.

### **Question** 14.

What is a heat sink?

#### Answer:

Heat sink is a device which absorbs the unnecessary heat generated in the transistor and radiates it to surroundings and protects it.

**Question** 15. Write the relation between  $I_{CE0}$  and  $I_{CB0}$ . **Answer:**  $I_{CE0} = (I+p)I_{CB0}$ .

### **Two Marks and Three Marks Questions**

#### **Question** 1.

Explain the biasing of a transistor.

#### Answer:

The application of suitable DC voltage across the transistor terminals is called biasing of the transistor.

The reasons for biasing of a transistor are:

- 1. To make the operating point to be at the centre of the load line.
- 2. To make the collector current independent of temperature variations.
- 3. To maintain the operating point constant even though transistor is replaced by another of same type.

#### **Question** 2.

Draw the DC load line and mark the endpoints. **Answer:** 



**Question** 3. Mention any two biasing circuits. **Answer:** 

- Fixed bias
- Collector to base feedback.

## **Question** 4.

What are the quiescent point and load line?

### Answer:

Operating point is the zero signal values of collector  $I_c$  and collector to emitter voltage  $V_{CE}$  of a transistor. DC load line is a straight line drawn on the output characteristics representing output DC voltage and corresponding direct current under no signal conditions.

### **Question** 5.

Why is the voltage divider bias circuit preferred in the amplification process? **Answer:** 

The operating point does not depend upon the value of  $\beta$  of the transistor. Hence the operating point does not change its position due to rise in temperature or replacing a transistor of different p value. Hence voltage divider bias provides excellent stabilisation and is preferred to other biasing methods.

### Question 6.

What is leakage current? Mention different types of leakage currents.

### Answer:

Leakage current is current through a device due to the motion of minority charge carriers under reverse bias conditions.

Different leakage currents are:

- Collector to base leakage current with emitter open (I<sub>CBO</sub>).
- Collector to emitter leakage current with base open  $(1_{CEO})$ .

## **Question** 7.

What are advantages of voltage divider bias? **Answer:** 

- Q point gets stabilised very well as the stabilication factor does not depend upon p.
- It provides better amplification when used in amplifiers.

## Question 8.

What is the significance of load line?

### Answer:

Load line is a straight line drawn on output characteristics representing output DC voltage and corresponding output direct current under no signal condition. Load line contains every possible operating point for the circuit.

### **Question** 9.

Explain the collector to base leakage current and collector to emitter leakage current.

#### Answer:

1. The current flowing through the collector when the emitter terminal is open is called collector to base leakage current with emitter open  $I_{CB0}$ . This leakage current doubles for every 10°c rise in temperature. This leakage current also increases when the reverse bias voltage is increased.

2. The current flowing through the collector when base terminal is open is called collector to emitter leakage current with base open. This current increases with increase in temperature. This leakage current increases when the reverse bias voltage is increased.

### Question 10.

What is thermal runaway? Explain.

#### Answer:

The self destruction of an unbiased transistor due to increase in temperature and hense increase in leakage current.

#### **Question** 11.

On what factors does stabilisation of a transistor amplifier depend upon? **Answer:** 

The value of p and temperature.

### **Question** 12.

What is meant by heat sink? Mention its importance.

### Answer:

Heat sink is a device which absorbs unwanted heat generated in the transistor and radiates to the surroundings. A copper conductor with different shapes are connected to the device to take out heat from the device. With heat sink, power rating of the device increases.

### Question 13.

What is unbiased transistor? Explain the need for biasing the transistor.

#### Answer:

Unbiased transistor is a transistor with its terminals not connected to any source. Biasing a transistor is applying a suitable DC voltage across the transistor terminals to operate the transistor in the desired region.

Need for biasing a transistor are:

- To make operating point to be at the centre of load line for faithful amplification.
- To make collector current independent of temperature variations.

• To make operating point stabilised even when one transistor is replaced by another.

## **Question** 14.

Describe the steps to draw dc load line for a transistor. **Answer:** Consider the equation  $V_{CE} = V_{cc}-I_c \ge R_c$ To plot the point on x-axis, put I =0 in equ (1)  $V_{CE} = V_{cc}$ To plot the point on y-axis, put  $V_{CE}$ =0, in equ (1)

eqn(1) =  $I_{Csat} = \frac{V_{CC}}{R_C}$ 

The load lines is drawn joining these end points



## Question 15.

What is voltage divider bias? Mention its advantages.

## Answer:

Voltage divider bias is the method of biasing a transistor. The voltage drop across forword biases the base emitter junction. This causes the base current and hence collector current to flow in zero signal condition and establishes operating point.

Advantages:

- It offers excellent stabilisation and hence Q point does not shift.
- when used in amplifiers, it provides better amplification.

# **Question** 16.

Explain the steps required to draw the dc load line for voltage divider bias. **Answer:** 



Applying KVL to the circuit,  $V_{cc} = I_cR_e + V_{ce} + I_cR_e$   $V_{cc} = I_c(R_c+R_e) + V_{ce}$ .  $V_{cc} = V_{cc} - I_c(R_c+R_e)$  ......(1) To plot the point on x axis, put  $I_c = 0$ . Equ (1) becomes,  $V_{CE} = V_{CC}$ To plot the point on y axis, put  $V_{CE}=0$ . Equ (1) becomes,

 $\mathrm{I}_{c} = rac{\mathrm{V}_{cc}}{\mathrm{R}_{c} + \mathrm{R}_{\epsilon}}$ 

DC load line is drawn from the end points and is plotted as shown below:



#### **Question** 17.

Name the different biasing circuits. Which biasing circuit is better recommeded to get faithful amplification?

#### Answer:

Different biasing circuits are:

• Fixed bias

- collector to base bias.
- Emitter feedback bias.
- Voltage divider bias. voltage divider biasing circuit is the best method to get faithful amplification.

### **Five Marks Questions**

#### **Question** 1.

Derive the expressions for the Q point in voltage divider bias. **Answer:** 



Voltage across R2 is

$$\mathrm{V}_2 = rac{\mathrm{V}_{CC}\mathrm{R}_2}{\mathrm{R}_1 + \mathrm{R}_2}$$

Applying KVL to the base circuit , We get  $V_2$  =  $V_{BE}$  +  $V_2$   $V_2$  =  $V_{BE}$  +  $I_E$   $R_E$ 

$$\therefore I_E R_E = V_2 - V_{BE}$$

$$I_E = \frac{V_2 - V_{BE}}{R_E}$$
As  $I_E \simeq I_C$ 

$$I_C = I_{CQ}$$

$$= \frac{V_2 - V_{BE}}{R_E} \longrightarrow (1)$$
Applying KVL to collector circuit

$$V_{CC} = I_C R_C + V_{CE} + V_E$$

$$V_{CC} = I_C R_C + V_{CE} + I_E R_E$$

$$V_{CC} = I_C (R_C + R_E) + V_{CE} \quad \{\because I_E - I_C\}$$

$$V_{CEQ} = V_{CC} - I_{CQ} (R_C + R_E) \longrightarrow (2)$$

Equations 1 and 2 define operating point or Q point.

#### **Question** 2.

How does stabilisation takes place in voltage divider bias? Explain **Answer:** 



From voltage divider theorem, voltage across the resistor  $R_2$  is

$$\mathbf{Y} = \mathbf{A}\overline{\mathbf{C}}\overline{\mathbf{D}} + \overline{\mathbf{B}}\mathbf{D} + \overline{\mathbf{A}}\mathbf{D} + \mathbf{B}\mathbf{C}\overline{\mathbf{D}}$$

Apply KVL to base emitter loop  $V_2 = V_{BE +} V_E$   $V_2 = V_{BE} = I_E R_E$  $V_{BE} = V_2 - I_E R_E$  Whenever  $I_c$  increases, due to increase in  $\beta$  or temperature, the current  $I_E$  also increases ( $I_E=I_C$ ). Hence  $I_E R_E$  increases and  $V_{BE}$  decreases due to which base current  $I_B$  decreases. Decrease in L decreases  $I_c$  and thus the operating point gets stabilised.

#### **Question** 3.

Find the end points of the load line for the circuit given below: **Answer:** 



Applying KVL to collector circuit, We get, Vcc =I<sub>c</sub>Rc + Vce 16 =I<sub>c</sub> x 4 x 10<sup>3</sup>+V<sub>ce</sub> .....(1) Put I<sub>c</sub> = 0 in equation (1), we get, V<sub>CE</sub> ( cut off) = Vcc = 16 V This is cut off point on the x-axis. Put V<sub>CE</sub> = 0 in equation (1), we get, 16 = IC x 4 x 10<sup>3</sup>+ 0, IC = 16 x 10<sup>-3</sup> /4 = 4mA.

This is saturation point on y axis



**Question** 4. Applying KVL to collector circuit, we have **Answer:** 



Applying KVL to collector circuit, We get,  $V_{cc} = i_c R_e + V_{CE}$   $40 = I_c x \ 10 x \ 10^3 + V_{ce} \dots (1)$ Put  $I_c = 0$ ,  $40 = V_{CE}$  (cut off) This is cut off point on x-axis.



#### **Question** 5.

Draw the load line for the following circuit: **Answer:** 



$$V_{2} = V_{CC} \left(\frac{R_{2}}{R_{1} + R_{2}}\right)$$
  
=  $12 \times \frac{8.6k}{33k + 8.6k}$   
=  $12 \times \frac{8.6 \times 10^{3}}{(33 + 8.6) \times 10^{3}}$   
=  $2.48V$ .  
$$I_{E} = \frac{V_{2} - V_{BE}}{R_{E}}$$
  
=  $\frac{2.48 - 0.7}{560}$   
=  $3.2$ mA.  
As  $I_{C} = I_{E}$ ,  
 $I_{C} = 3.2$ mA =  $I_{CQ}$   
 $V_{CE} = V_{CC} - I_{C}(R_{C} + R_{E})$   
=  $12 - 3.2 \times 10^{-3} [1800 + 560]$   
 $V_{CEQ} = 7.5$ V.

# **Question** 6.

Find the operating point of the circuit given below: **Answer:** 



$$V_{2} = V_{BE} + I_{ERE}$$

$$I_{E} = \frac{V_{2} - V_{BE}}{R_{E}}$$

$$= \frac{3.58 - 0.7}{560}$$

$$= 0.00514A$$

$$= 5.14mA.$$
As  $I_{E} = I_{C}$ 

$$I_{CQ} = I_{E}$$

$$= 5.14mA.$$
Apply KVL to collector circuit
$$V_{CC} = I_{C} R_{C} + V_{CE} + I_{E} R_{E}$$

$$V_{CC} = I_{C} (R_{C} + R_{E}) + V_{CE}$$

$$V_{CEQ} = V_{CC} - I_{C} (R_{C} + R_{E})$$

$$= 10 - 5.14 \times 10^{-3} (1000 + 560)$$

$$= 10 - 8.018$$

$$= 1.98 \text{ Volt.}$$